

# **RS6G100BGTB1** Datasheet

www.digi-electronics.com



RS6G100BGTB1-DG
Rohm Semiconductor
RS6G100BGTB1
NCH 40V 100A, HSOP8, POWER MOSFE
N-Channel 40 V 100A (Tc) 3W (Ta), 59W (Tc) Surface Mount 8-HSOP

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
RS6G100BGTB1	Rohm Semiconductor
Series:	Product Status:
-	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
40 V	100A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
4.5V, 10V	3.4mOhm @ 90A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
2.5V @ 1mA	24 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	1510 pF @ 20 V
FET Feature:	Power Dissipation (Max):
-	3W (Ta), 59W (Tc)
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
8-HSOP	8-PowerTDFN

## **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	

8541.29.0095



Nch 40V 100A Power MOSFET

V <sub>DSS</sub>	40V
R <sub>DS(on)</sub> (Max.)	3.4mΩ
I <sub>D</sub>	±100A
P <sub>D</sub>	59W

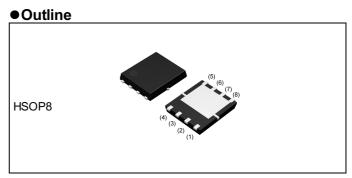
## Features

- 1) Low on resistance
- 2) High power small mold package (HSOP8)
- 3) Pb-free plating ; RoHS compliant
- 4) Halogen free

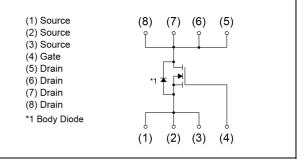
Application

Switching

5) 100% Rg and UIS tested



#### Inner circuit



## Packaging specifications

	Packing	Embossed Tape
Туре	Reel size (mm)	330
	Tape width (mm)	12
	Quantity (pcs)	2500
	Taping code	TB1
	Marking	RS6G100BG

## • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V <sub>DSS</sub>	40	V
Continuous drain current	V <sub>GS</sub> = 10V	I <sub>D</sub> *1	±100	А
Pulsed drain current		$I_{DP}^{*2}$	±400	А
Gate - Source voltage		V <sub>GSS</sub>	±20	V
Avalanche current, single pulse		I <sub>AS</sub> *3	20	А
Avalanche energy, single pulse		E <sub>AS</sub> *3	30	mJ
Power dissipation		P <sub>D</sub> <sup>*1</sup>	59	W
		P <sub>D</sub> <sup>*4</sup>	3.0	W
Junction temperature		Tj	150	°C
Operating junction and storage tempe	T <sub>stg</sub>	-55 to +150	°C	

#### Thermal resistance

Deremeter	Currence of	Values			1 1
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	2.1	°C/W
Thermal resistance, junction - ambient	$R_{thJA}^{*4}$	-	-	41.7	°C/W

## •Electrical characteristics (T<sub>a</sub> = 25°C)

Devenuetor	O: reals al	Caraditiana		Values		l lunit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	40	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	28.9	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V	-	-	2	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	-	-	±200	nA
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 1mA$	1.0	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-4.6	-	mV/°C
Static drain - source	D *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 90A	-	2.6	3.4	
on - state resistance	$R_{DS(on)}^{*5}$	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 50A	-	4.6	6.5	mΩ
Gate resistance	R <sub>G</sub>	-	-	1.6	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  * <sup>5</sup>	V <sub>DS</sub> = 5V, I <sub>D</sub> = 50A	21	-	-	S

\*1 T<sub>c</sub>=25°C, Limited only by maximum temperature allowed.

\*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

- \*3 L  $\simeq$  0.1mH, V\_{DD} = 20V, R\_G = 25 $\Omega$ , Starting T\_j = 25°C Fig.3-1,3-2
- \*4 Mounted on a Cu board (40×40×0.8mm)
- \*5 Pulsed



## •Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Cumph of	Conditions		Values		l loit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	1510	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 20V	-	690	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	80	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 20V, V_{GS}$ = 10V	-	15	-	
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 50A	-	16	-	-
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L \simeq 0.4\Omega$	-	46	-	ns
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	18	-	

## • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Sumbol			Values			1 1
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
<b>T</b>			V <sub>GS</sub> = 10V	-	24.0	-	
Total gate charge	Q <sub>g</sub> *5	$V_{DD} \simeq 20V$		-	11.8	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 50A	V <sub>GS</sub> = 4.5V	-	3.7	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5			-	4.3	-	

## •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Sumbol	Symbol Conditions Values				Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I <sub>S</sub>	T <sub>a</sub> = 25℃	-	-	45	А
Pulse forward current	I <sub>SP</sub> *2	$T_a = 25 C$	-	-	400	А
Forward voltage	$V_{SD}^{*5}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 45A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 45A, V <sub>GS</sub> =0V	-	36.5	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/µs	-	34.0	-	nC



#### • Electrical characteristic curves

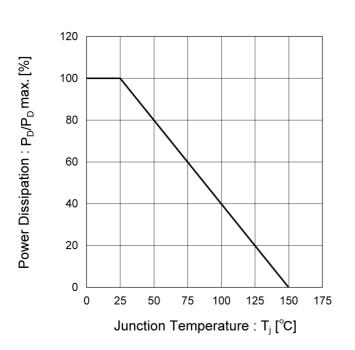


Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

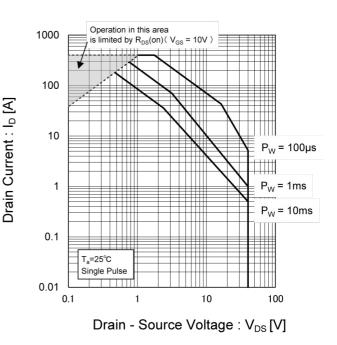
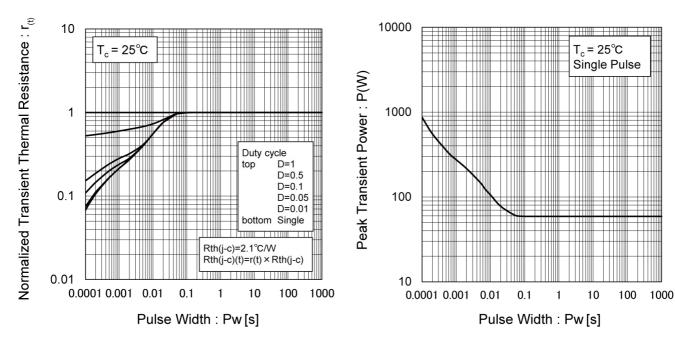


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

Fig.4 Single Pulse Maximum Power Dissipation



Drain Current : I<sub>D</sub> [A]

#### • Electrical characteristic curves

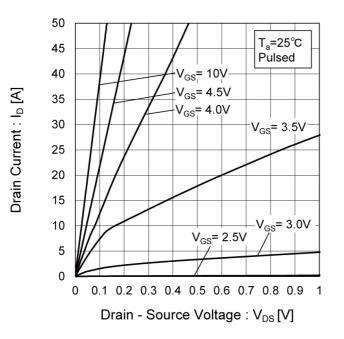


Fig.7 Breakdown Voltage vs.

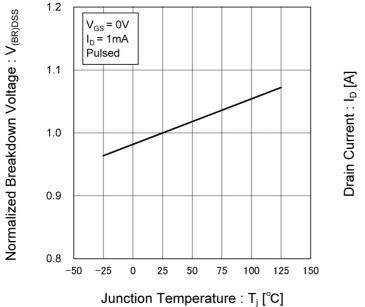
Junction Temperature

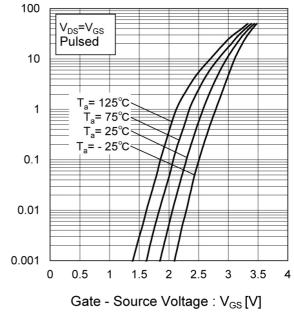
## Fig.5 Typical Output Characteristics(I)

50 T<sub>a</sub>=25°C 45 ′<sub>GS</sub>=\_10V Pulsed V<sub>GS</sub>= 4.5V 40 /<sub>GS</sub>= 4.0V 35 -V<sub>GS</sub>= 3.5V 30 25 V<sub>GS</sub>= 3.0V 20 15 10 V<sub>,GS</sub>= 2.5V 5 0 5 0 2 3 4 6 7 8 9 10 1 Drain - Source Voltage : V<sub>DS</sub> [V]

## Fig.6 Typical Output Characteristics(II)

Fig.8 Typical Transfer Characteristics





## • Electrical characteristic curves

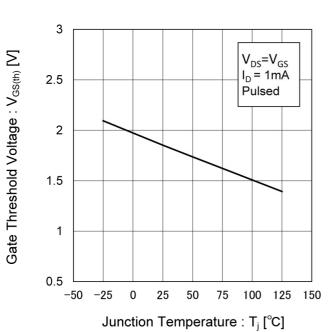


Fig.11 Drain Current Derating Curve

Fig.9 Gate Threshold Voltage vs. Junction Temperature

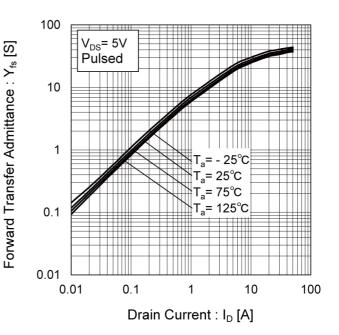
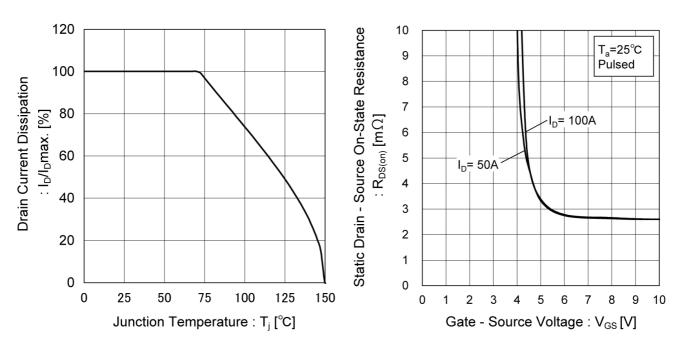
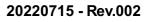


Fig.10 Forward Transfer Admittance vs.

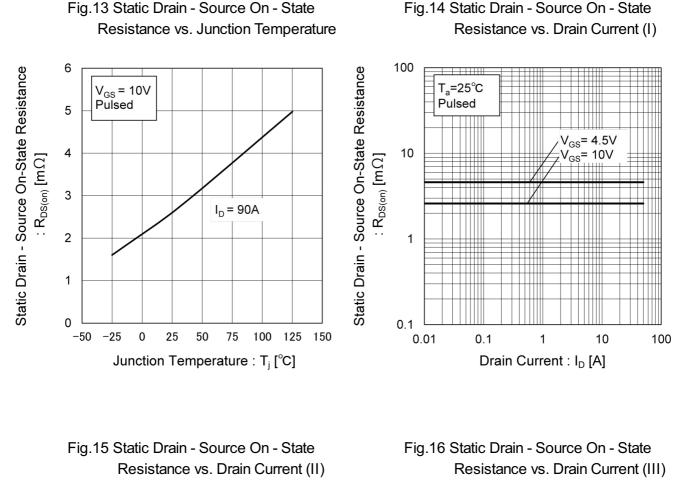
**Drain Current** 

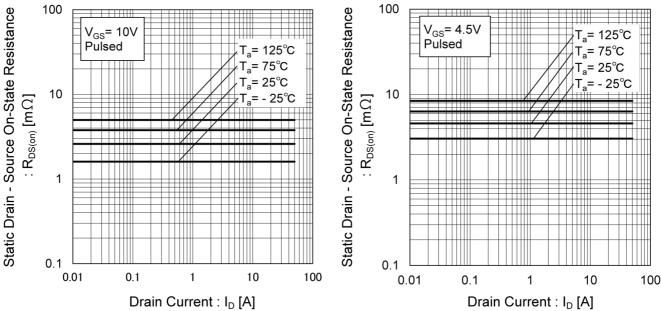
Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





## •Electrical characteristic curves





ROHIT

## • Electrical characteristic curves

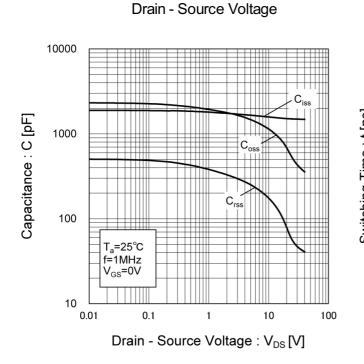


Fig.17 Typical Capacitances vs.

## Fig.18 Switching Characteristics

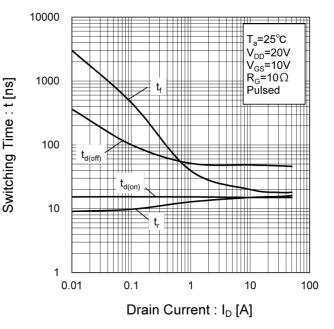


Fig.19 Typical Gate Charge

Gate - Source Voltage : V<sub>GS</sub> [V]

10

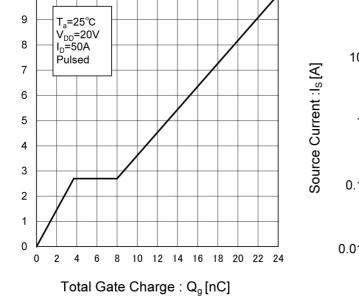
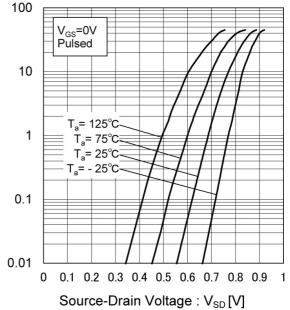


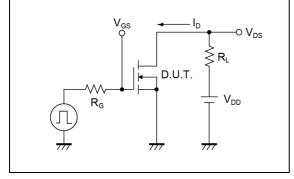
Fig.20 Source Current vs. Source Drain Voltage



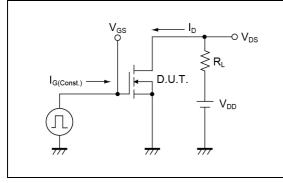


#### Measurement circuits

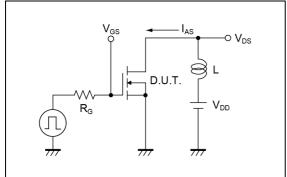
Fig.1-1 Switching Time Measurement Circuit



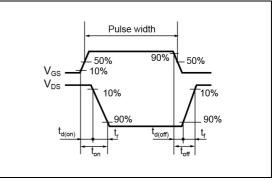
#### Fig.2-1 Gate Charge Measurement Circuit



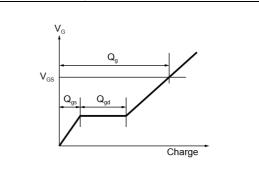
#### Fig.3-1 Avalanche Measurement Circuit



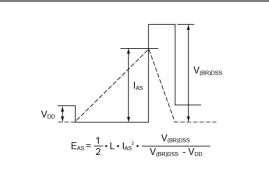
#### Fig.1-2 Switching Waveforms



#### Fig.2-2 Gate Charge Waveform



#### Fig.3-2 Avalanche Waveform



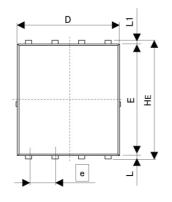
#### Notice

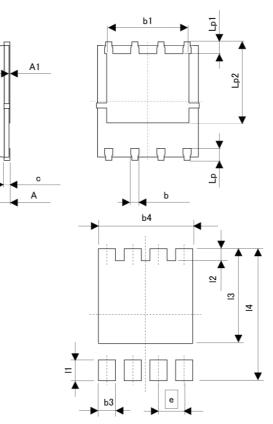
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

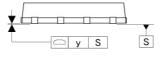


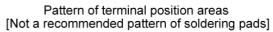
#### Dimensions

HSOP8 (TB1)





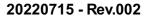




	HES			
DIM		TERS		
	MIN	MAX	MIN	MAX
A	0.90	1.10	0.035	0.043
A1	0.00	0.05	0.000	0.002
b	0.33	0.42	0.013	0.017
b1	3.61	3.96	0.142	0.156
С	0.20	0.30	0.008	0.012
D	4.80	5.00	0.189	0.197
E	5.70	5.80	0.224	0.228
е	1.	27	0.0	)50
HE	5.90	6.10	0.232	0.240
L	0.06	0.20	0.002	0.008
L1	0.06	0.20	0.002	0.008
Lp	0.51	0.71	0.020	0.028
Lp1	0.41	0.61	0.016	0.024
Lp2	3.79	4.39	0.149	0.173
DIM	MILIME	ETERS	INC	HES
DIV	MIN	MAX	MIN	MAX
b3	-	0.68	-	0.027
b4	-	4.06	-	0.160
1	-	0.81	-	0.032
12	-	0.71	-	0.028
13	-	4.49		0.177
14	-	6.20	-	0.244

10/10

Dimension in mm/inches



## Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Application	ations
--	--------

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	
CLASSⅣ		CLASSI	CLASSⅢ

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

#### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

#### **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

#### **General Precaution**

- 1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.



## **OUR CERTIFICATE**

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

DCI	DCI	DCI	
QUALITY MANAGEMENT SYSTEM	ENVIRONMENTAL MANAGEMENT SYSTEM	OCCUPATIONAL HEALTH & SAFETY	0428248
CERTIFICATE	CERTIFICATE	MANAGEMENT SYSTEM CERTIFICATE	CERTIFICATE OF INCORPORATION
DIGI ELECTRONICS HK LIMITED	DIGI ELECTRONICS HK LIMITED	DIGI ELECTRONICS HK LIMITED	A. A. B. A. B. W. Dentify weldy that
FLAT RENOS 1054, NO HANG COMMERCIAL CONTREL OVERTA NUCH STREET, MONGHO	PLATERALISE 25/7, HO HORD COMMERCIAL COMMERCIAL MATA YORK STREET, MONORO	PLATERALIS 25/7, HO HONG COMMITTING COMMITTING A MATA YORN STREET, MONORO	DELE REACTION OF A COMPANY OF
TLATING STAF. HO HAVE COMMERCIAL COLUMN 2 FIETA TURN STREET, MCMORD	RAMEANING 2547, HO HONO COMMINICAL DI NERA VIEN STREET, INCHORO	RAMENDE 254, HO HING COMMITCIN, EN HINA VUEN STREET, MONGHO	
GB/T 19001-2016 kdt ISO9001:2015	GB/T 24001-2016 idt ISO14001:2015	GB/T45001-2020 idt ISO45001:2018	It Bit B B B B B B B B B B B B B B B B B
No file	for the	To the second of the second se	A=0 , $A=A=A=0$ , $A=0$ , $A=0$ , $C=0$ (Theoler 422 of the Laws of Hang Kong), and that this company is $X=A=0$ , $A=0$
			* Smith company.
	Indicational and Party and Indiana	terturinen Hill	farmed on 23 James 201.
endowthater bes. H. An HED Contraction Theory Contraction Theory	Mark 1991 Annu 1991 Hans 1991 Annu 1991 Constants Resuge	Interfactions fam Wilks 2001	Kin
000			●混合約51日の日本式を発展か MAABLE DEMO
			Perghanar of Companies Hung-Keng Special Administrative Region
Territoria de la 163 Centra la 164	Gentland inter H an Hit Gentland faith an Hit	Gentrate Insuring Mark Mills Gentrate Fairly Security Security	4. Npm: 公司委員会司的政策改將:医方式不懂找了你公司支援支援分别帮助公司管理成本所 员先的现象情。
The state is a state of the sta	The adults areas of the indicates of the adult has been been been to reach the state of the adults are solved, seen of the or reach the adult has been adole provide a state of the origination of the adults and solved, seen of the or reach the adult has been adole provide adult of the adult has been adult and the adult of the adult of the solved of the adult of the solved of the adult of the solved of the adult of the	The states sense (1) is addressed of the states and particle sequences and not so under the states are obligations and it is addressed and addressed and particle sequences and the state and the states are obligations and the states and the states and the states are states are states are states and the states are statest are states are statest are	Pageteleter of a company same with the Companies Rigging takes not confer any tools main lights or any other Reliastual pagenty rights to request of the sampany, same or any part Remail.
A delay de 2014 sector del referencien base des las relativada com	DEI Certification Ltd	Access for 12 for any has been been been been been and the second second	





Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.